iai Electricai Specifications LT6206



Dual Single Supply 3V, 100MHz Video Op-Amp

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FEATURES

- 400V/us Slew Rate
- 100MHz Gain Bandwidth Product
- Wide Supply Range 2.7V to 12.6V
- Output Swings Rail-to-Rail
- Input Common Mode Range Includes Ground
- Low Cost
- High Output Drive: 50mA
- Channel Separation: 90dB at 10MHz
 Specified on 3V, 5V, and ±5V Supplies
- Input Offset Voltage: 1mV
- 8-Pin MSOP Package
- Operating Temperature Range: -40°C to 85°C
- Low Power Dissipation: 20mW Per Amplifier on Single 5V

APPLICATIONS

- Video Line Driver
- Automotive Displays
- RGB Amplifiers
- Coaxial Cable Drivers

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Low Voltage High Speed Signal Processing

DESCRIPTION

The LT®6206 is a low cost dual voltage feedback amplifier that features a 100MHz gain-bandwidth product, a 400V/ µs slew rate and a 50mA output current. The LT6206 has an input range which includes ground and an output which swings within 60mV of either supply rail, making it well suited for single supply operation.

The LT6206 maintains its performance for supplies from 2.7V to 12.6V and is specified at 3V, 5V and ±5V. The inputs can be driven beyond the supplies without damage or phase reversal of the output. Isolation between channels is high, over 90dB at 10MHz.

The LT6206 is available in an 8-lead MSOP package with the standard op amp pinout. The device is specified over the commercial and industrial temperature range.

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TYPICAL APPLICATION

Baseband Video Splitter/Cable Driver 3.3V $= 499\Omega$ $1\mu F$ $= 75\Omega$ V_{IN} 75Ω V_{IN} 75Ω V_{IN} 75Ω V_{IN} 75Ω V_{IN} 75Ω V_{IN} $F_{3dB} \approx 50MHz$ $I_{S} \leq 25mA$

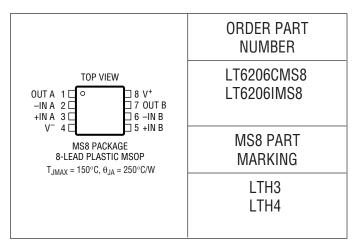
Output Step Response Vout OV VIN OV VS = 3.3V VIN = 0.1V TO 1.1V f = 10MHz

ABSOLUTE MAXIMUM RATINGS

(Note 1)

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Input Current±10m.	/ ۱
Input Voltage Range (Note 2)±V	S
Output Short-Circuit Duration (Note 3) Indefinit	te
Pin Current When Exceeding Supplies (Note 9) 25m.	A
Operating Temperature Range40°C to 85°	C
Specified Temperature Range (Note 4) – 40°C to 85°	C
Storage Temperature Range65°C to 150°	С
Maximum Junction Temperature 150°	С
Lead Temperature (Soldering, 10 sec)300°	C

PACKAGE/ORDER INFORMATION



Consult LTC Marketing for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICS The \bullet denotes specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = 3V, 0V; V_S = 5V, 0V; V_{CM} = V_{OUT} = 1V$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
$\overline{V_{0S}}$	Input Offset Voltage			1	3.5	mV	
			•			5	mV
	Input Offset Voltage Match				1	3	mV
	(Channel-to-Channel) (Note 5)		•			4	mV
	Input Offset Voltage Drift (Note 6)		•		7	15	μV/°C
I _B	Input Bias Current		•		18	30	μА
I _{OS}	Input Offset Current		•		0.6	3	μА
	Input Noise Voltage	0.1Hz to 10Hz			2		μV _{P-P}
e _n	Input Noise Voltage Density	f = 10kHz			9		nV/√Hz
i _n	Input Noise Current Density	f = 10kHz			4		pA/√Hz
	Input Resistance	$V_{IN} = 0V \text{ to } V_{CC} - 2V$			1		MΩ
	Input Capacitance				2		pF
CMRR	Common Mode Rejection Ratio	$V_{CM} = 0$ to $V_{CC} - 2V$	•	78	90		dB
	Input Voltage Range		•	0		V _{CC} – 2	V
PSRR	Power Supply Rejection Ratio	V _S = 3V to 12V V _{CM} = V _{OUT} = 0.5V	•	67	75		dB

ELECTRICAL CHARACTERISTICS The ullet denotes specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = 3V, 0V; V_S = 5V, 0V; V_{CM} = V_{OUT} = 1V$, unless otherwise noted.

SYMBOL	PARAMETER CONDITIONS			MIN	TYP	MAX	UNITS	
	Minimum Supply Voltage		•			2.7	V	
A _{VOL}	Large-Signal Voltage Gain	$V_S = 5V$, $V_0 = 0.5V$ to 4.5V, $R_L = 1k$ $V_S = 5V$, $V_0 = 1V$ to 3V, $R_L = 150\Omega$ $V_S = 3V$, $V_0 = 0.5V$ to 2.5V, $R_L = 1k$	•	30 5 20	100 20 60		V/mV V/mV V/mV	
V _{OL}	Output Voltage Swing Low (Note 7)	No Load, Input Overdrive = 30mV I _{SINK} = 5mA V _S = 5V, I _{SINK} = 25mA V _S = 3V, I _{SINK} = 15mA	•		10 75 300 200	25 150 500 350	mV mV mV	
V _{OH}	Output Voltage Swing High (Note 7)	No Load, Input Overdrive = 30mV I _{SOURCE} = 5mA V _S = 5V, I _{SOURCE} = 25mA V _S = 3V, I _{SOURCE} = 15mA	•		60 140 650 300	100 250 1200 500	mV mV mV	
I _{SC}	Short-Circuit Current	V _S = 5V, Output Shorted to GND	•	35 25	50		mA mA	
		V _S = 3V, Output Shorted to GND	•	30 20	40		mA mA	
Is	Supply Current per Amplifier		•		4	5 5.75	mA mA	
GBW	Gain Bandwidth Product	f = 2MHz	•	65	100		MHz	
SR	Slew Rate	$V_S = 5V$, $A_V = 2$, $R_F = R_G = 1k$ $V_O = 1V$ to 4V, Measure from 1.5V to 3.5V			400		V/µs	
	Channel Separation	f = 10MHz			90		dB	
FPBW	Full Power Bandwidth	V _{OUT} = 2V _{P-P} (Note 8)			64		MHz	
t_S	Settling time to 3%	$V_S = 5V$, $\Delta V_{OUT} = 2V$, $A_V = -1$, $R_L = 150\Omega$			20		ns	
	Differential Gain Differential Phase	V_S = 5V, A_V = 2, R_L = 150 Ω , Black Level =1V V_S = 5V, A_V = 2, R_L = 150 Ω , Black Level =1V			0.05 0.08		% Deg	

The ullet denotes specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = \pm 5V$; $V_{CM} = V_{OUT} = 0V$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
$\overline{V_{0S}}$	Input Offset Voltage				1.3	4.5	mV
			•			6	mV
	Input Offset Voltage Match				1	3	mV
	(Channel-to-Channel) (Note 5)		•			4	mV
	Input Offset Voltage Drift (Note 6)		•		10	18	μV/°C
I _B	Input Bias Current		•		18	30	μΑ
I _{OS}	Input Offset Current		•		0.6	3	μΑ
	Input Noise Voltage	0.1Hz to 10Hz			2		μV _{P-P}
e _n	Input Noise Voltage Density	f = 10kHz			9		nV/√Hz
i _n	Input Noise Current Density	f = 10kHz			4		pA/√Hz
	Input Resistance	$V_{IN} = -5V \text{ to } 3V$	•		1		MΩ
	Input Capacitance				2		pF

ELECTRICAL CHARACTERISTICS The ullet denotes specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = \pm 5V$; $V_{CM} = V_{OUT} = 0V$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
CMRR	Common Mode Rejection Ratio	V _{CM} = -5V to 3V	•	78	90		dB
	Input Voltage Range		•	-5		3	V
PSRR	Power Supply Rejection Ratio	$V_S = \pm 2V$ to $\pm 6V$	•	67	75		dB
A _{VOL}	Large-Signal Voltage Gain	$V_0 = -4V \text{ to } 4V, R_L = 1k$	•	50	133		V/mV
		$V_0 = -3V \text{ to } 3V, R_L = 150\Omega$	•	7.5	20		V/mV
	Output Voltage Swing	No Load, Input Overdrive = 30mV I _{OUT} = ±5mA I _{OUT} = ±25mA	•	±4.88 ±4.75 ±3.8	±4.92 ±4.85 ±4.35		mV mV mV
I _{SC}	Short-Circuit Current	Short to Ground	•	±40 ±30	±60		mA mA
Is	Supply Current per Amplifier		•		4.5	5.6 6.5	mA mA
GBW	Gain Bandwidth Product	f = 2MHz	•	65	100		MHz
SR	Slew Rate	$A_V = -1$, $R_L = 1k$ $V_0 = -4V$ to 4V, Measure from -3V to 3V		350	550		V/µs
	Channel Separation	f = 10MHz			90		dB
FPBW	Full Power Bandwidth	V _{OUT} = 8V _{P-P} (Note 8)		14	22		MHz
t_S	Settling Time to 3%	$\Delta V_{OUT} = 2V$, $A_V = -1$, $R_L = 150\Omega$			20		ns
	Differential Gain Differential Phase	$\begin{array}{l} A_V=2,\ R_L=150\Omega,\ Black\ Level=1V\\ A_V=2,\ R_L=150\Omega,\ Black\ Level=1V \end{array}$			0.05 0.1		% Deg

Note 1: Absolute Maximum ratings are those values beyond which the life of a device may be impaired.

Note 2: The inputs are protected by back-to-back diodes. If the differential input voltage exceeds 1.4V, the input current should be limited to less than 10mA.

Note 3: A heat sink may be required to keep the junction temperature below absolute maximum. This depends on the power supply voltage and how many amplifiers are shorted.

Note 4: The LT6206C is guaranteed to meet specified performance from 0° C to 70° C and is designed, characterized and expected to meet specified performance from -40° C to 85° C but is not tested or QA sampled at these temperatures. The LT6206I is guaranteed to meet specified performance from -40° C to 85° C.

Note 5: Matching parameters are the difference between the two amplifiers of the LT6206.

Note 6: This parameter is not 100% tested.

Note 7: Output voltage swings are measured between the output and power supply rails.

Note 8: Full power bandwidth is calculated from the slew rate measurement: FPBW = $SR/2\pi V_{PEAK}$.

Note 9: There are reverse biased ESD diodes on all inputs and outputs. If these pins are forced beyond either supply, unlimited current will flow through these diodes. If the current is transient in nature and limited to less than 25mA, no damage to the device will occur.

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS		
LT1253/LT1254	Low Cost Dual and Quad Video Amplifiers	-3dB Bandwidth = 90MHz, Current Feedback		
LT1395/LT1396/LT1397	Single Dual Quad 400MHz Current Feedback Amplifiers	0.1dB Flatness to 100MHz, 80mA Output Drive		
LT1675	RGB Multiplexer with Current Feedback Amplifiers	-3dB Bandwidth = 250MHz, 100MHz Pixel Switching		
LT1809/LT1810	Single/Dual, 180MHz, Rail-to-Rail Input and Output Amplifiers	350V/µs Slew Rate, Shutdown, Low Distortion –90dBc at 5MHz		
LT6550/LT6551	3.3V Triple and Quad Video Amplifiers	Internal Gain of 2, 110MHz –3dB Bandwidth, Input Common Modes to Ground		